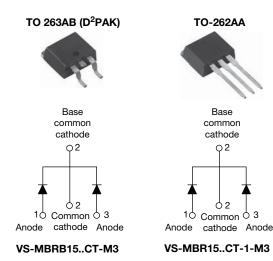


Vishay Semiconductors

RoHS

High Performance Schottky Rectifier, 2 x 7.5 A



| PRODUCT SUMMAP | PRODUCT SUMMARY | | | | | | |
|----------------------------------|---|--|--|--|--|--|--|
| I _{F(AV)} | 2 x 7.5 A | | | | | | |
| V _R | 35 V, 45 V | | | | | | |
| V _F at I _F | 0.57 V | | | | | | |
| I _{RM} max. | 15 mA at 125 °C | | | | | | |
| T _J max. | 150 °C | | | | | | |
| E _{AS} | 7 mJ | | | | | | |
| Package | TO-263AB (D ² PAK), TO-262AA | | | | | | |
| Diode variation | Common cathode | | | | | | |

FEATURES

- 150 °C T_J operation
- Center tap TO-220 package
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy compliant encapsulation for enhanced mechanical strength and moisture resistance compliant encapsulation for enhanced mechanical strength and moisture resistance encapsulation for enhanced mechanical encapsulation encapsulation for enhanced mechanical encapsulation encapsulation for enhanced mechanical encapsulation enc
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-MBR(B)15... center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | |
|-----------------------------------|---|-------------|-------|--|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | | |
| I _{F(AV)} | Rectangular waveform | 15 | А | | | | |
| V _{RRM} | | 35/45 | V | | | | |
| I _{FSM} | t _p = 5 μs sine | 690 | А | | | | |
| V _F | 7.5 A _{pk} , T _J = 125 °C | 0.57 | V | | | | |
| TJ | | -65 to +150 | °C | | | | |

| VOLTAGE RATINGS | | | | | |
|--------------------------------------|------------------|---------------------------------------|---------------------------------------|-------|--|
| PARAMETER | SYMBOL | VS-MBRB1535CT-M3 VS-MBR1535CT-1-M3 | VS-MBRB1545CT-M3 VS-MBR1545CT-1-M3 | UNITS | |
| Maximum DC reverse voltage | V _R | 35 | 45 | V | |
| Maximum working peak reverse voltage | V _{RWM} | | 45 | v | |

Revision: 15-Aug-15

Document Number: 94948

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay Semiconductors

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|---|--|--------------------|---|--|--------|-------|--|
| PARAMETER | | SYMBOL | SYMBOL TEST CONDITIONS | | VALUES | UNITS | |
| Maximum averageper legforward currentper device | | 1 | T ₂ = 121 °C, roto | od V_ | 7.5 | | |
| | | I _{F(AV)} | $T_{C} = 131 \text{ °C}$, rated V_{R} | | 15 | | |
| Maximum peak one cycle non-repetitive surge | | | 5 μs sine or 3 μs rect. pulse | Following any rated load condition and with rated V _{RRM} applied | 690 | А | |
| | | IFSM | Surge applied at rated load conditions halfwave, single phase, 60 Hz | | 150 | | |
| Non-repetitive avalanche energy per leg | | E _{AS} | T _J = 25 °C, I _{AS} = 2 A, L = 3.5 mH | | 7 | mJ | |
| Repetitive avalanche current per leg | | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _B typical | | 2 | А | |

| PARAMETER | SYMBOL | TEST CO | NDITIONS | VALUES | UNITS | |
|---------------------------------------|---|---|-----------------------------|--------|-------|--|
| | | 15 A | T _J = 25 °C | 0.84 | | |
| Maximum forward voltage drop | V _{FM} ⁽¹⁾ | 7.5 A | T 105 %C | 0.57 | V | |
| | | 15 A | - T _J = 125 °C | 0.72 | | |
| Maximum instantaneous reverse current | I _{RM} ⁽¹⁾ | T _J = 25 °C | Deted DC veltage | 0.1 | 0 | |
| Maximum instantaneous reverse current | | T _J = 125 °C | Rated DC voltage | 15 | mA | |
| Maximum junction capacitance | um junction capacitance C _T V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C | | ge 100 kHz to 1 MHz), 25 °C | 400 | pF | |
| Typical series inductance | Ls | Measured from top of terminal to mounting plane | | 8.0 | nH | |
| Maximum voltage rate of change | dV/dt | Rated V _R | 10 000 | V/µs | | |

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

| THERMAL - MECHA | ANICAL SP | ECIFICA | TIONS | | | |
|---|-----------|-------------------|--------------------------------------|-------------|------------|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum junction temperature range | | TJ | | -65 to +150 | °C | |
| Maximum storage temperature range | | T _{Stg} | | -65 to +175 | U | |
| Maximum thermal resistance, junction to case per leg | | R _{thJC} | DC operation | 3.0 | | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth and greased | 0.50 | | |
| Maximum thermal resistance, junction to ambient | | R _{thJA} | DC operation | 60 | | |
| Approvimate weight | | | | 2 | g | |
| Approximate weight | | | | 0.07 | oz. | |
| minimun | | | | 6 (5) | kgf · cm | |
| Mounting torque | maximum | | | 12 (10) | (lbf · in) | |
| Marking davias | | | Case style D ² PAK | MBRB1 | 545CT | |
| Marking device | | | Case style TO-262 | MBR15 | 45CT-1 | |

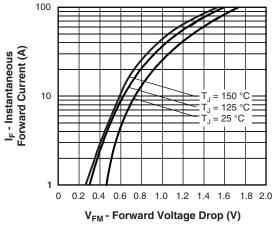
Revision: 15-Aug-15

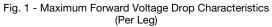


VS-MBRB15..CT-M3, VS-MBR15..CT-1-M3

Vishay Semiconductors

www.vishay.com





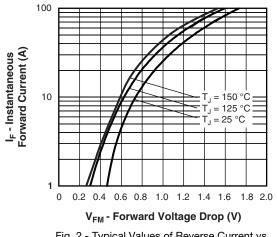


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

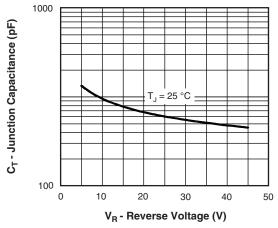


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

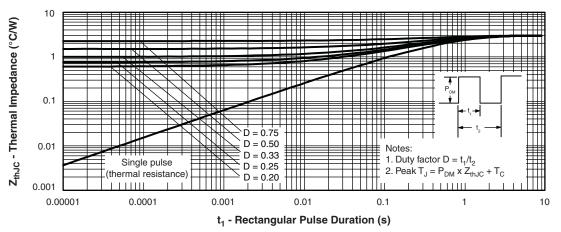
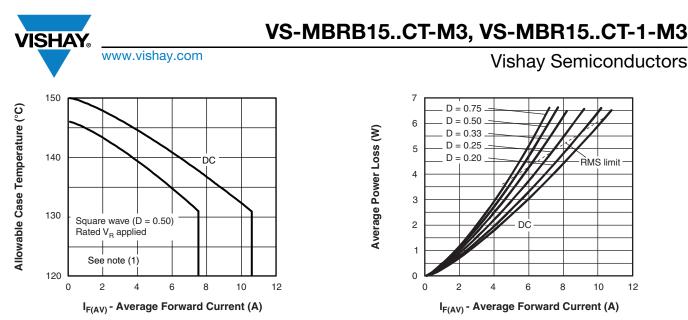
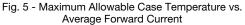
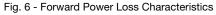


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

Revision: 15-Aug-15 3 Document Number: 94948 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>







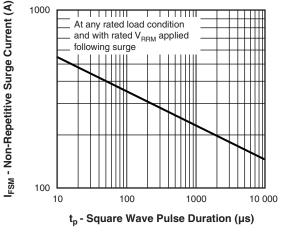
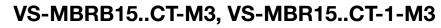


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

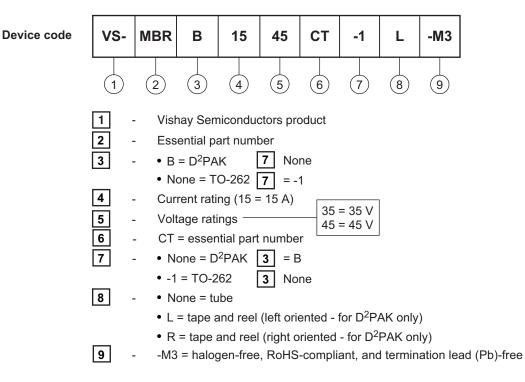
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = Rated V_R



Vishay Semiconductors

ORDERING INFORMATION TABLE

www.vishay.com



| ORDERING INFORMATION | | | | | | |
|----------------------|------------------|------------------------|--------------------------|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | |
| VS-MBRB1535CT-M3 | 50 | 1000 | Antistatic plastic tubes | | | |
| VS-MBRB1535CTR-M3 | 800 | 800 | 13" diameter reel | | | |
| VS-MBRB1535CTL-M3 | 800 | 800 | 13" diameter reel | | | |
| VS-MBR1535CT-1-M3 | 50 | 1000 | Antistatic plastic tubes | | | |
| VS-MBRB1545CT-M3 | 50 | 1000 | Antistatic plastic tubes | | | |
| VS-MBRB1545CTR-M3 | 800 | 800 | 13" diameter reel | | | |
| VS-MBRB1545CTL-M3 | 800 | 800 | 13" diameter reel | | | |
| VS-MBR1545CT-1-M3 | 50 | 1000 | Antistatic plastic tubes | | | |

| | LINKS TO RELATED DOCUMENTS | | | | | | |
|--------------------------|-------------------------------|--------------------------|--|--|--|--|--|
| Dimensions | TO-263AB (D ² PAK) | www.vishay.com/doc?95046 | | | | | |
| Dimensions | TO-262AA | www.vishay.com/doc?95419 | | | | | |
| Part marking information | TO-263AB (D ² PAK) | www.vishay.com/doc?95444 | | | | | |
| Part marking information | TO-262AA | www.vishay.com/doc?95443 | | | | | |
| Packaging information | | www.vishay.com/doc?95032 | | | | | |
| SPICE model | | www.vishay.com/doc?95294 | | | | | |

Revision: 15-Aug-15 5 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000

Document Number: 94948

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

www.vishay.com

SHA



| SYMBOL | MILLIM | IETERS | INC | HES | NOTES | SYMBOL | MILLIM | IETERS | INC | HES | NOTES |
|--------|--------|--------|-------|-------|-------|--------|--------|--------|-------|-------|-------|
| STMBOL | MIN. | MAX. | MIN. | MAX. | NOTES | STWDUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| A | 4.06 | 4.83 | 0.160 | 0.190 | | D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | е | 2.54 | BSC | 0.100 | BSC | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | L | 1.78 | 2.79 | 0.070 | 0.110 | |
| С | 0.38 | 0.74 | 0.015 | 0.029 | | L1 | - | 1.65 | - | 0.066 | 3 |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | L3 | 0.25 | BSC | 0.010 | BSC | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1

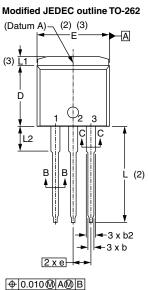


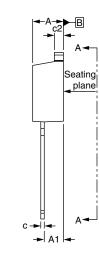
Outline Dimensions

Vishay Semiconductors

TO-262

DIMENSIONS in millimeters and inches

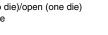


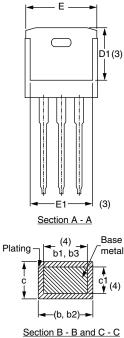


Lead assignments



Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode





Scale: None

| SYMBOL | MILLIM | ETERS | INC | NOTEO | |
|--------|----------|-------|-------|-------|-------|
| SYMBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.06 | 4.83 | 0.160 | 0.190 | |
| A1 | 2.03 | 3.02 | 0.080 | 0.119 | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.38 | 0.74 | 0.015 | 0.029 | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 |
| D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| е | 2.54 BSC | | 0.10 | 0 BSC | |
| L | 13.46 | 14.10 | 0.530 | 0.555 | |
| L1 | - | 1.65 | - | 0.065 | 3 |
| L2 | 3.56 | 3.71 | 0.140 | 0.146 | |

Notes

Revision: 04-Oct-10

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

Document Number: 95419 For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.